

SPRAGUE-GOODMAN ELECTRONICS, INC.

SUPER HYPERABRUPT TUNING VARACTOR DIODES SURFACE MOUNT LOW PARASITIC (SMLP) PACKAGES

FEATURES

- Mesa Epitaxial Silicon Construction
- Silicon Dioxide Passivated
- Fits Footprint for SOD-323, SOD-123 and smaller
- High Frequency (VHF to 8 GHz)
- Available on Carrier and Reel
- Available in chip form (add suffix -000)
- Two package styles including lower cost, flat top version
- Alternate notched termination version available, contact factory for outline drawing

SPECIFICATIONS

Reverse breakdown voltage (at 10 μ A DC) at 25°C: 30 V min
 Maximum reverse leakage current (at -10 V) at 25°C: 0.05 μ A DC
 Device dissipation (at 25°C): 250 mW (derated linearly to zero at +125°C)
 Operating Junction temperature: -65°C to +125°C
 Storage temperature: -65°C to +125°C

MODEL NUMBER	CAPACITANCE RATIO C_T (pF) at 0 V / C_T (pF) at -4V min	DIODE CAPACITANCE C_T (pF) at -4V ($\pm 10\%$)	CAPACITANCE RATIO C_T (pF) at -4V / C_T (pF) at -30V min	Q min at -4 V (50 MHz)
GVD91300-XXX	1.5	0.8	1.45	3900
GVD91301-XXX	1.6	1.0	1.55	3800
GVD91302-XXX	1.7	1.2	1.60	3700
GVD91303-XXX	1.8	1.5	1.65	3600
GVD91304-XXX	1.9	1.8	1.70	3500
GVD91305-XXX	2.0	2.2	1.75	3400
GVD91306-XXX	2.0	2.7	1.80	3300
GVD91307-XXX	2.1	3.3	1.85	3100
GVD91308-XXX	2.1	3.9	1.90	2700
GVD91309-XXX	2.2	4.7	1.95	2600
GVD91310-XXX	2.2	5.6	2.00	2500

TERMINATIONS (GOLD PLATED)

DOT INDICATES CATHODE END

EPOXY ENCAPSULANT

SIDE VIEW FOR -01X

EPOXY ENCAPSULANT

SIDE VIEW FOR -11X

Dimensions are in in/mm
 Tolerance is $\pm 0.003/0.08$
 unless otherwise indicated

DASH NO.	A	B	C	C1 max	D	K	L	M
-011	0.10	0.050	0.035	—	0.015 \pm 0.004	0.030	0.070	0.112
-111	2.5	1.3	0.89	—	0.38 \pm 0.1	0.76	1.8	2.84
				0.050				1.3
-012	0.12	0.060	0.035	—	0.020 \pm 0.005	0.030	0.080	0.132
-112	3.0	1.5	0.89	—	0.51 \pm 0.1	0.76	2.0	3.35
				0.050				1.3
-013	0.200	0.100	0.035	—	0.020 \pm 0.005	0.030	0.120	0.212
-113	5.08	2.54	0.89	—	0.51 \pm 0.1	0.76	3.05	5.38
				0.050				1.3
-014	0.075	0.050	0.035	—	0.015 \pm 0.004	0.030	0.070	0.087
-114	1.9	1.3	0.89	—	0.38 \pm 0.1	0.76	1.8	2.2
				0.050				1.3
-015	0.062	0.042	0.030	—	0.011 \pm 0.003	0.020	0.060	0.072
-115	1.6	1.1	0.76	—	0.28 \pm 0.08	0.051	1.5	1.8
				0.050				1.3

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